

Sir:

Transmitted herewith for filing is the Patent Application of:

Inventor: MIN-HSIUNG CHIANG, JIN-YUAN LEE AND JENN MING HUANG

For: METHOD FOR FORMING HIGH PURITY SILICON OXIDE FIELD OXIDE ISOLATION REGION

JC586 U.S. PTO



Enclosed are:

06/04/99

- ☒ 1 sheets of drawing(s) - formal.
- ☒ An assignment of the invention to Taiwan Semiconductor Manufacturing Company
- ☐ An associate power of attorney

The filing fee has been calculated as shown below:

	(Col. 1)	(Col. 2)	OTHER THAN A SMALL ENTITY	
FOR:	NO. FILED	NO. EXTRA	RATE	FEE
BASIC FEE				\$ 760.
TOTAL CLAIMS	10 -20=	0	x 18 =	\$ 0.
INDEP CLAIMS	2 -3=	0	x 78 =	\$ 0.
MULTIPLE DEPENDENT CLAIM PRESENTED			+ 260 =	
SUB TOTAL				\$ 760.
ASSIGNMENT				\$40.
TOTAL				\$ 800.

- ☒ Please charge my Deposit Account No. 19-0033 in the amount of \$ 800. A duplicate copy of this sheet is enclosed.
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- ☒ Any additional filing fees required under 37 CFR \$1.16.
- ☒ Any patent application processing fees under 37 CFR \$1.17.

Respectfully submitted,
Stephen B. Ackerman
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